TL505C

Analog-to-Digital Converter

The TL505C is an analog-to-digital converter building block designed for use with TMS1000 type microprocessors. It contains the analog elements (operational amplifier, comparator, voltage reference, analog switches, and switch drivers) necessary for a unipolar automatic-zeroing dual-slope converter. The logic for the dual-slope conversion can be performed by the associated MPU as a software routine or can be implemented with other components, such as the TL502 logic-control device.

The high-impedance MOS inputs permit the use of less expensive, lower value capacitors for the integration and offset capacitors and permit conversion speeds from 20 per second to 0.05 per second.

Rochester Electronics Manufactured Components

Rochester branded components are manufactured using either die/wafers purchased from the original suppliers or Rochester wafers recreated from the original IP. All recreations are done with the approval of the OCM.

Parts are tested using original factory test programs or Rochester developed test solutions to guarantee product meets or exceeds the OCM data sheet.

Quality Overview

- ISO-9001
- AS9120 certification
- Qualified Manufacturers List (QML) MIL-PRF-38535
    - Class Q Military
    - Class V Space Level
- Qualified Suppliers List of Distributors (QSLD)
    - Rochester is a critical supplier to DLA and meets all industry and DLA standards.

Rochester Electronics, LLC is committed to supplying products that satisfy customer expectations for quality and are equal to those originally supplied by industry manufacturers.

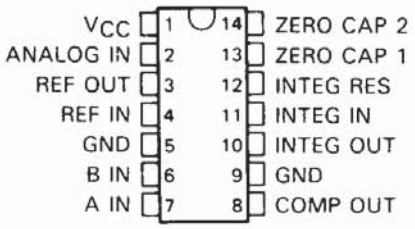
The original manufacturer's datasheet accompanying this document reflects the performance and specifications of the Rochester manufactured version of this device. Rochester Electronics guarantees the performance of its semiconductor products to the original OEM specifications. 'Typical' values are for reference purposes only. Certain minimum or maximum ratings may be based on product characterization, design, simulation, or sample testing.

TL505C
ANALOG-TO-DIGITAL CONVERTER

D2366, OCTOBER 1977—REVISED FEBRUARY 1989

- 3-Digit Accuracy (0.1%)
- 10-Bit Resolution
- Automatic Zero
- Internal Reference Voltage
- Single-Supply Operation
- High-Impedance MOS Input
- Designed for Use with TMS1000 Type Microprocessors for Cost-Effective High-Volume Applications
- BI-MOS Technology
- Only 40 mW Typical Power Consumption

N PACKAGE
(TOP VIEW)



Caution. This device has limited built-in gate protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

description

The TL505C is an analog-to-digital converter building block designed for use with TMS1000 type microprocessors. It contains the analog elements (operational amplifier, comparator, voltage reference, analog switches, and switch drivers) necessary for a unipolar automatic-zeroing dual-slope converter. The logic for the dual-slope conversion can be performed by the associated MPU as a software routine or can be implemented with other components, such as the TL502 logic-control device.

The high-impedance MOS inputs permit the use of less expensive, lower value capacitors for the integration and offset capacitors and permit conversion speeds from 20 per second to 0.05 per second.

The TL505C is a product of TI's BI-MOS process, which incorporates bipolar and MOSFET transistors on the same monolithic circuit. The TL505C is characterized for operation from 0°C to 70°C.

TEXAS INSTRUMENTS
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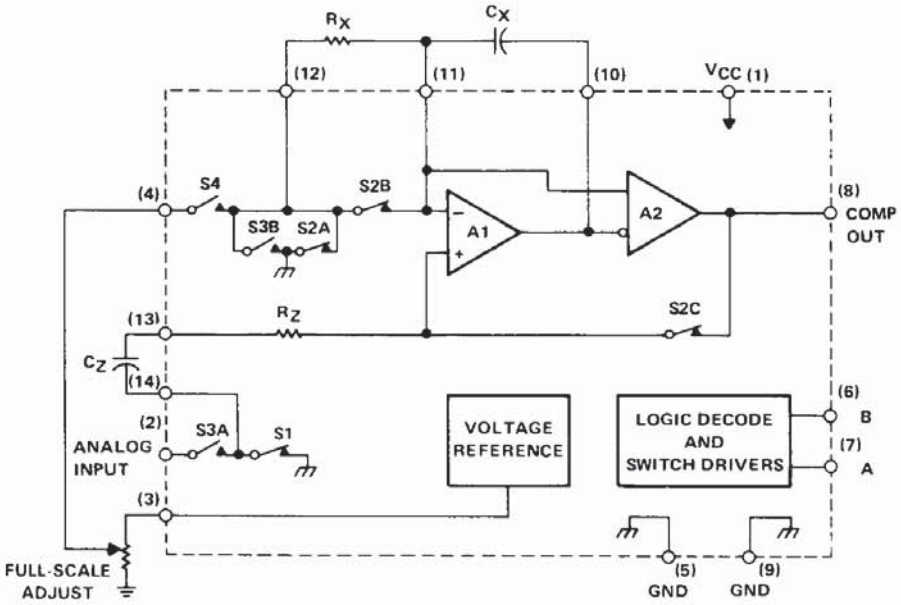
functional block diagram



NOTE: Analog and digital GND are internally connected together.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage, V_{CC} (see Note 1) . . . . . 18 V
Input voltage, pins 2, 4, 6, and 7 . . . . . V_{CC}
Continuous total dissipation at (or below) 25°C free-air temperature (see Note 2) . . . . . 1150 mW
Operating free-air temperature range . . . . . 0°C to 70°C
Storage temperature range . . . . . −65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds . . . . . 260°C

NOTES: 1. Voltage values are with respect to the two ground terminals connected together.
2. For operation above 25°C free-air temperature, derate linearly to 736 mW at 70°C at the rate of 9.2 mW/°C.

recommended operating conditions

	MIN	NOM	MAX	UNIT
Supply voltage, V_{CC}	7	9	15	V
Analog input voltage, V_I	0		4	V
Reference input voltage, $V_{ref(I)}$	0.5		3	V
High-level input voltage at A or B, V_{IH}	3.6		$V_{CC}+1$	V
Low-level input voltage at A or B, V_{IL}	0.2		1.8	V
Integrator capacitor, C_X	See "component selection"			
Integrator resistor, R_X	0.5		2	MΩ
Integration time, t_1	16.6		500	ms
Operating free-air temperature, T_A	0		70	°C

electrical characteristics, V_{CC} = 9 V, $V_{ref(I)}$ = 1 V, T_A = 25°C, connected as shown in Figure 1 (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{OH}	High-level output voltage at pin 8	I_{OH} = 0	7.5	8.5		V
I_{OH}	High-level output current at pin 8	V_{OH} = 7.5 V		−100		μA
V_{OL}	Low-level output voltage at pin 8	I_{OL} = 1.6 mA		200	400	mV
V_{OM}	Maximum peak output voltage swing at integrator output	$R_X \geq$ 500 kΩ	$V_{CC}-2$	$V_{CC}-1$		V
$V_{ref(0)}$	Reference output voltage	I_{ref} = −100 μA	1.15	1.22	1.35	V
αV_{ref}	Temperature coefficient of reference output voltage	T_A = 0°C to 70°C		±100		ppm/°C
I_{IH}	High-level input current into A or B	V_I = 9 V		1	10	μA
I_{IL}	Low-level input current into A or B	V_I = 1 V		10	200	μA
I_I	Current into analog input	V_I = 0 to 4 V, A input at 0 V		±10	±200	pA
I_{IB}	Total integrator input bias current			±10		pA
I_{CC}	Supply current	No load		4.5	8	mA

system electrical characteristics, V_{CC} = 9 V, $V_{ref(I)}$ = 1 V, T_A = 25°C, connected as shown in Figure 1 (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Zero error	V_I = 0		0.1	0.4	mV
Linearity error	V_I = 0 to 4 V		0.02	0.1	%FS
Ratiometric reading	$V_I = V_{ref(I)} \approx$ 1 V	0.998	1.000	1.002	
Temperature coefficient of ratiometric reading	$V_{ref(I)}$ constant and ≈ 1 V, T_A = 0°C to 70°C		±10		ppm/°C

DEFINITION OF TERMS

Zero Error

The intercept (b) of the anolog-to-digital converter system transfer function y = mx + b, where y is the digital output, x is the analog input, and m is the slope of the transfer function, which is approximated by the ratiometric reading.

Linearity Error

The maximum magnitude of the deviation from a straight line between the end points of the transfer function.

Ratiometric Reading

The ratio of negative integration time (t_2) to positive time (t_1).

PRINCIPLES OF OPERATION

A block diagram of an MPU system using the TL505C is shown in Figure 1. The TL505C operates in a modified positive-integration, three-step, dual-slope conversion mode. The A/D converter waveforms during the conversion process are illustrated in Figure 2.

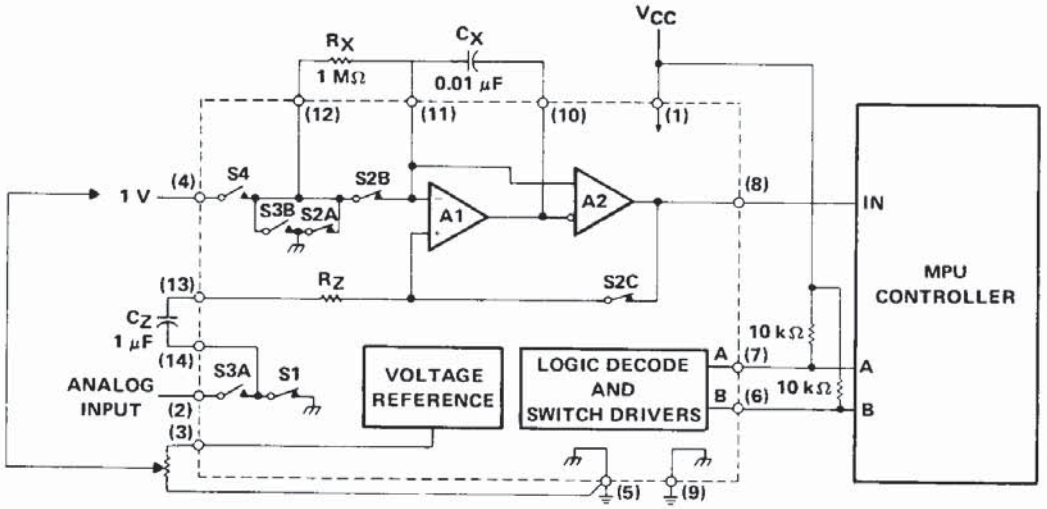
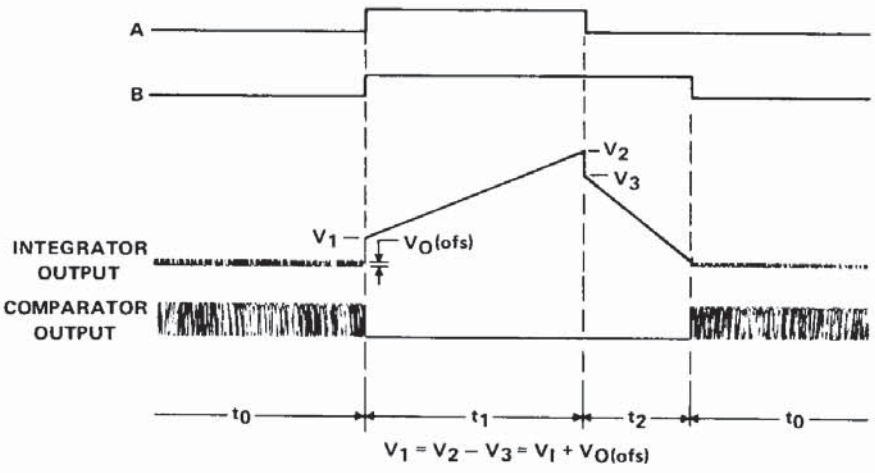


FIGURE 1. FUNCTIONAL BLOCK DIAGRAM OF TL505C INTERFACE WITH A MICROPROCESSOR SYSTEM



FUNCTION TABLE

CONTROLS A	CONTROLS B	ANALOG SWITCHES CLOSED
L	L	S1, S2
H	H	S3
L	H	S1, S4

H = V_{IH}, L = V_{IL}

FIGURE 2. CONVERSION PROCESS TIMING DIAGRAMS

PRINCIPLES OF OPERATION (Continued)

The first step of the conversion process is the auto-zero period t_0. By the end of this period, the integrator offset is stored in the autozero capacitor, and the offset of the comparator is stored in the integrator capacitor. To achieve this end, the MPU takes the A and B inputs low, which closes S1 and S2. The output of the comparator is connected to the input of the integrator through the low-pass filter consisting of R_Z and C_Z. The closed loop of A1 and A2 seeks a null condition in which the offsets of the integrator and comparator are stored in C_Z and C_X, respectively. This null condition is characterized by a high-frequency oscillation at the output of the comparator. The purpose of S2B is to shorten the amount of time required to reach the null condition.

At the conclusion of t_0, the MPU takes the A and B inputs both high, which closes S3 and opens all other switches. The input signal V_I is applied to the noninverting input of A1 through C_Z. V_I is then positively integrated by A1. Since the offset of A1 is stored in C_Z, the change in voltage across C_X is due to only the input voltage. Since the input is integrated in a positive integration during t_1, the output of A1 will be the sum of the input voltage, the integral of the input voltage, and the comparator offset, as shown in Figure 2. The change in voltage across capacitor C_X (V_{CX}) during t_1 is given by

$$\Delta V_{CX(1)} = \frac{V_I t_1}{R_1 C_X} \tag{1}$$

where $R_1 = R_X + R_{S3B}$ and R_{S3B} is the resistance of switch S3B.

At the end of t_1, the MPU takes the A input low and the B input high, which closes S1 and S4 and opens all other switches. In this state, the reference is integrated by A1 in a negative sense until the integrator output reaches the comparator threshold. At this point, the comparator output goes high. This change in state is sensed by the MPU, which terminates t_2 by again taking the A and B inputs both low. During t_2, the change in voltage across C_X is given by

$$\Delta V_{CX(2)} = \frac{V_{ref} t_2}{R_2 C_X} \tag{2}$$

where $R_2 = R_X + R_{S4} + R_{ref}$ and R_{ref} is the equivalent resistance of the reference divider.

Since $\Delta V_{CX1} = -\Delta V_{CX2}$, equations (1) and (2) can be combined to give

$$V_I = V_{ref} \frac{R_1 \cdot t_2}{R_2 \cdot t_1} \tag{3}$$

This equation is a variation on the ideal dual-slope equation, which is

$$V_I = V_{ref} \frac{t_2}{t_1} \tag{4}$$

Ideally then, the ratio of R_1/R_2 would be exactly equal to one. In a typical TL505C system where $R_X = 1\ M\Omega$, the scaling error introduced by the difference in R_1 and R_2 is so small that it can be neglected, and equation (3) reduces to (4).

PRINCIPLES OF OPERATION (Continued)

component selection

The autozero capacitor C_Z should be within the recommended range of operating conditions and should have low leakage characteristics. Most film-dielectric capacitors and some tantalum capacitors provide acceptable results. Ceramic and aluminum capacitors are not recommended because of their relatively high leakage characteristics.

The integrator capacitor C_X should also be within the recommended range and must have good voltage linearity and low dielectric absorption. For 10-bit applications, polyster, polycarbonate, and other film dielectrics are usually suitable. If greater precision or stability is required, a polypropylene-dielectric capacitor similar to TRW's X363UW might be appropriate.

Stray coupling from the comparator output to any analog pin (in order of importance, 13, 11, 10, 2, 4) must be minimized to avoid oscillations. In addition, all power supply pins should be bypassed at the package, for example, by a 0.01-μF ceramic capacitor.

The time constant R_XC_X should be kept as near the minimum value as possible and is given by the formula:

$$\text{Minimum } R_XC_X = \frac{V_{I(max)}\, t_1}{(V_{CC} - 2\text{ V} - V_{I(max)})}$$

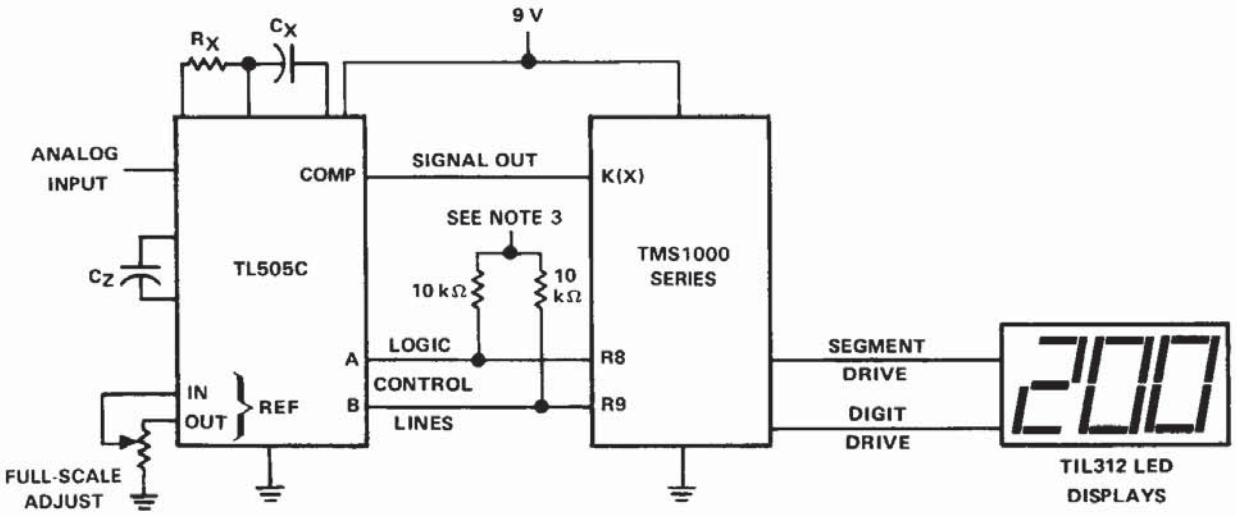
where:

t_1 = Input integration time in seconds,

$V_{I(max)}$ = the maximum value of the analog input voltage,

$V_{CC} - 2$ V = the maximum voltage swing of the integrator input.

TYPICAL APPLICATION DATA



NOTE 3: Connect to either 9 V or 0 V depending on which device in the TMS1000 series is used and how it is programmed.

FIGURE 3. TL505C IN CONJUNCTION WITH A TMS1000 SERIES MICROPROCESSOR FOR A 3-DIGITAL PANEL METER APPLICATION

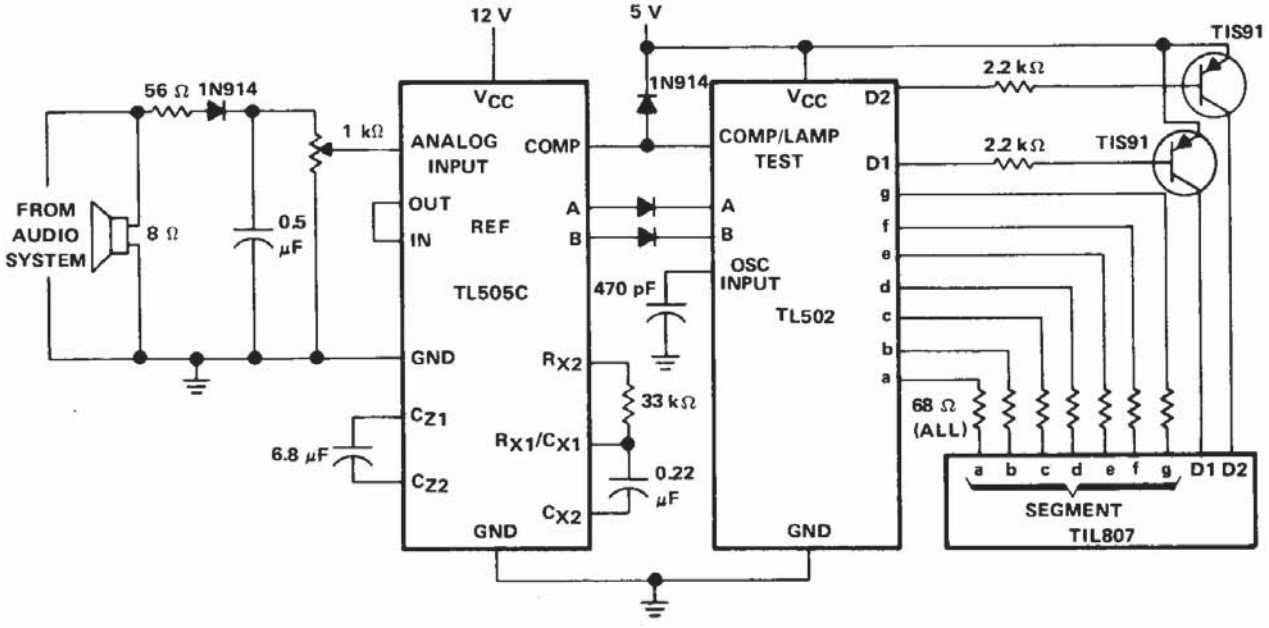


FIGURE 4. AUDIO PEAK POWER METER